



LM285/285B-1.2V
LM285/285B-2.5V
LM385/385B-1.2V
LM385/385B-2.5V

LOW POWER, BANDGAP VOLTAGE REFERENCES

FEATURES

- Output Tolerance 1% or 2%
- Output Voltage Option
 LM285/385-1.2V 1.235V
 LM285/385-2.5V 2.5V
- Wide Operating Current Range
 LM285/385-1.2V 15µA to 20mA
 LM285/385-2.5V 20µA to 20mA
- Temperature Coefficient 30ppm/°C
- Dynamic Impedance 0.6Ω
- TO-92-3 Plastic Package
- 8-Pin Plastic Narrow Body (SOIC) Package

APPLICATIONS

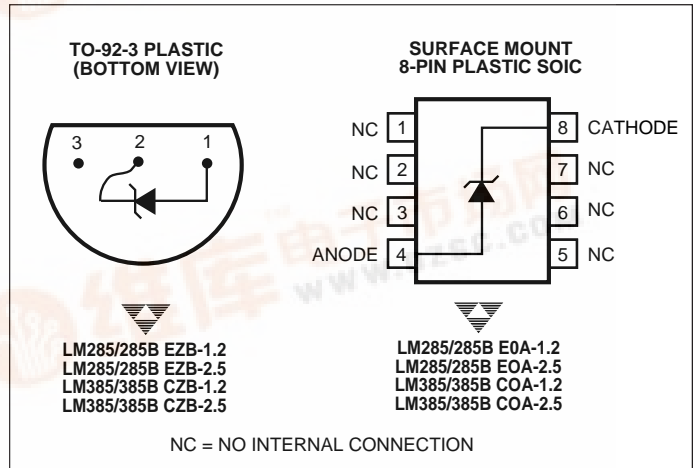
- ADC and DAC Reference
- Current Source Generation
- Threshold Detectors
- Power Supplies
- Multi-meters

GENERAL DESCRIPTION

The LM285/385-1.2V (1.235V output) and LM285/385-2.5V (2.5V output) are bipolar, two-terminal, bandgap voltage references that offer precision performance without premium price. These devices do not require thin-film resistors, greatly lowering manufacturing complexity and cost.

A 30ppm/°C output temperature coefficient and a 15µA to 20mA operating current range make these voltage references especially attractive for multimeter, data acquisition and telecommunications applications.

PIN CONFIGURATIONS



ORDERING INFORMATION

Part No.	Package	Temperature Range	Voltage	Tolerance
LM285BEOA-1.2	8-Pin SOIC	-40°C to +85°C	1.2	1%
LM285BEOA-2.5	8-Pin SOIC	-40°C to +85°C	2.5	1.5%
LM285BEZB-1.2	TO-92-3	-40°C to +85°C	1.2	1%
LM285BEZB-2.5	TO-92-3	-40°C to +85°C	2.5	1.5%
LM285EOA-1.2	8-Pin SOIC	-40°C to +85°C	1.2	2%
LM285EOA-2.5	8-Pin SOIC	-40°C to +85°C	2.5	3%
LM285EZB-1.2	TO-92-3	-40°C to +85°C	1.2	2%
LM285EZB-2.5	TO-92-3	-40°C to +85°C	2.5	3%
LM385BCOA-1.2	8-Pin SOIC	0°C to +70°C	1.2	1%
LM385BCOA-2.5	8-Pin SOIC	0°C to +70°C	2.5	1.5%
LM385BCZB-1.2	TO-92-3	0°C to +70°C	1.2	1%
LM385BCZB-2.5	TO-92-3	0°C to +70°C	2.5	1.5%
LM385COA-1.2	8-Pin SOIC	0°C to +70°C	1.2	2%
LM385COA-2.5	8-Pin SOIC	0°C to +70°C	2.5	3%
LM385CZB-1.2	TO-92-3	0°C to +70°C	1.2	2%
LM385CZB-2.5	TO-92-3	0°C to +70°C	2.5	3%

LOW POWER, BANDGAP VOLTAGE REFERENCES

LM285/285B-1.2V
LM285/285B-2.5V
LM385/385B-1.2V
LM385/385B-2.5V

ABSOLUTE MAXIMUM RATINGS*

Forward Current +10mA
 Reverse Current +30mA
 Storage Temperature Range – 65°C to +150°C
 Operating Temperature Range
 TO-92 Package – 40°C to +85°C
 Surface Mount Package – 40°C to +85°C

Lead Temperature (Soldering, 10 sec)
 TO-92 Package +300°C
 Surface Mount Package +300°C
 Power Dissipation
 Limited by Forward/Reverse Current

*Functional operation above the absolute maximum stress ratings is not implied.

ELECTRICAL CHARACTERISTICS: $T_A = +25^\circ\text{C}$, unless otherwise specified.

Symbol	Parameter	Test Conditions	LM285 / LM285B-1.2			LM385 / LM385B-1.2			Unit
			Min	Typ	Max	Min	Typ	Max	
$V_{(BR)R}$	Reverse Breakdown Voltage LM285B-1.2/LM385B-1.2 $T_A = T_{low}$ to T_{high} (Note 1) LM285-1.2V/LM385-1.2V $T_A = T_{low}$ to T_{high} (Note 1)	$I_R \leq 20\text{mA}$	1.223	1.235	1.247	1.223	1.235	1.247	V
			1.200	—	1.270	1.210	—	1.260	
			1.205	1.235	1.260	1.205	1.235	1.260	
			1.192	—	1.273	1.192	—	1.273	
I_{RMIN}	Minimum Operating Current $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)		—	8.0	15	—	8.0	15	μA
			—	—	20	—	—	20	
$\Delta V_{(BR)R}$	Reverse Breakdown Voltage Change with Current $I_{Rmin} = I_R = 1.0\text{mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1) $1.0\text{mA} = I_R = 20\text{mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)		—	—	1.0	—	—	1.0	mV
			—	—	1.5	—	—	1.5	
			—	—	10	—	—	20	
			—	—	20	—	—	25	
Z	Reverse Dynamic Impedance	$I_R = 100\mu\text{A}$	—	0.6	—	—	0.6	—	Ω
$\Delta V_{(BR)}/\Delta T$	Average Temperature Coefficient	$10\mu\text{A} \leq I_R \leq 20\text{mA}$	—	30	100	—	30	100	ppm/ $^\circ\text{C}$
S	Long Term Stability	$I_R = 100\mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	—	20	—	—	20	—	ppm/kHR

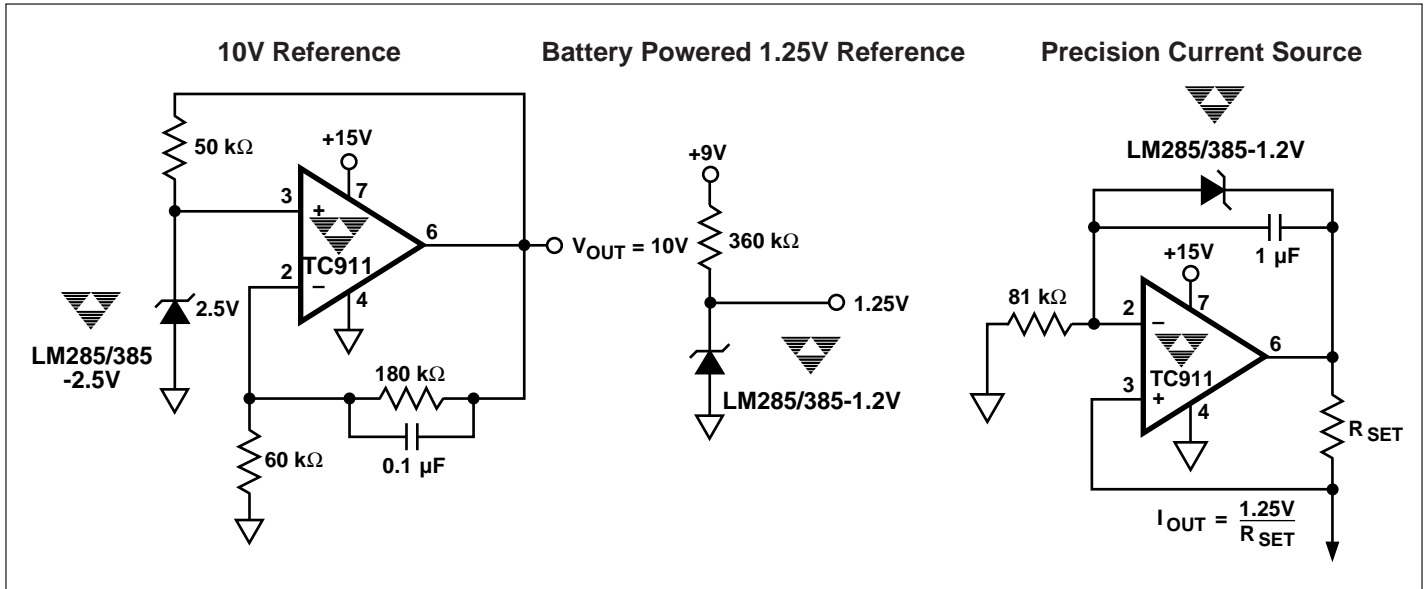
Symbol	Parameter	Test Conditions	LM285 / LM285B-2.5			LM385 / LM385B-2.5			Unit
			Min	Typ	Max	Min	Typ	Max	
$V_{(BR)R}$	Reverse Breakdown Voltage LM285B-2.5/LM385B-2.5 $T_A = T_{low}$ to T_{high} (Note 1) LM285-2.5V/LM385-2.5V $T_A = T_{low}$ to T_{high} (Note 1)	$I_R = 20\text{mA}$	2.462	2.5	2.538	2.462	2.5	2.538	V
			2.415	—	2.585	2.436	—	2.564	
			2.425	2.5	2.575	2.425	2.5	2.575	
			2.400	—	2.600	2.400	—	2.600	
I_{RMIN}	Minimum Operating Current $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)		—	13	20	—	13	20	μA
			—	—	30	—	—	30	
$\Delta V_{(BR)R}$	Reverse Breakdown Voltage Change with Current $I_{Rmin} = I_R = 1.0\text{mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1) $1.0\text{mA} = I_R = 20\text{mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)		—	—	1.0	—	—	2.0	mV
			—	—	1.5	—	—	2.5	
			—	—	10	—	—	20	
			—	—	20	—	—	25	
Z	Reverse Dynamic Impedance	$I_R = 100\mu\text{A}$	—	0.6	—	—	0.6	—	Ω
$\Delta V_{(BR)}/\Delta T$	Average Temperature Coefficient	$20\mu\text{A} \leq I_R \leq 20\text{mA}$	—	30	100	—	30	100	ppm/ $^\circ\text{C}$
S	Long Term Stability	$I_R = 100\mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	—	20	—	—	20	—	ppm/kHR

Note: 1. $T_{low} = -40^\circ\text{C}$ for LM285-1.2, LM285-2.5, LM285B-1.2, LM285B-2.5
 0°C for LM385-1.2, LM385B-1.2, LM385-2.5, LM385B-2.5

LOW POWER, BANDGAP VOLTAGE REFERENCES

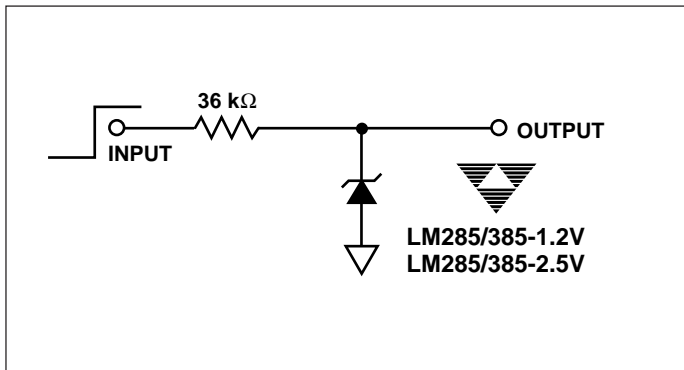
LM285/285B-1.2V
 LM285/285B-2.5V
 LM385/385B-1.2V
 LM385/385B-2.5V

TYPICAL APPLICATIONS



3

RESPONSE TIME TEST CIRCUIT

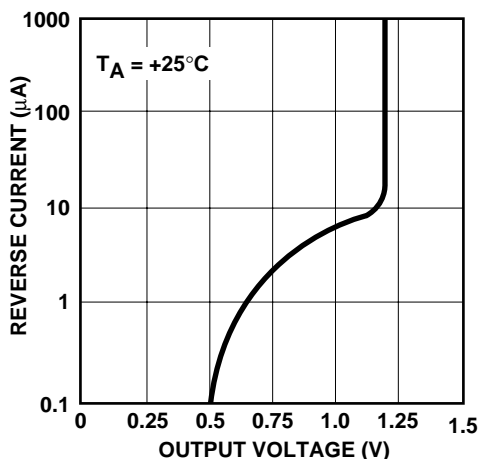


LM285/285B-1.2V
 LM285/285B-2.5V
 LM385/385B-1.2V
 LM385/385B-2.5V

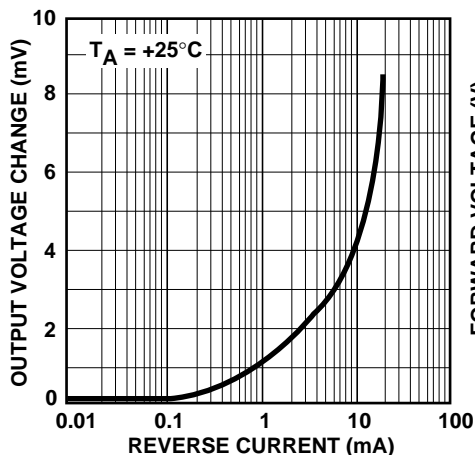
LOW POWER, BANDGAP
 VOLTAGE REFERENCES

TYPICAL CHARACTERISTICS

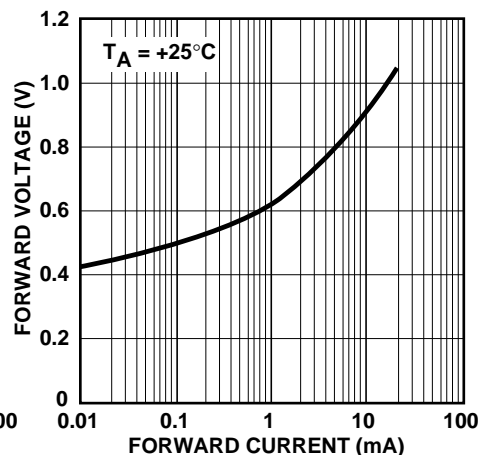
LM285/385-1.2V: Output Voltage vs Reverse Current



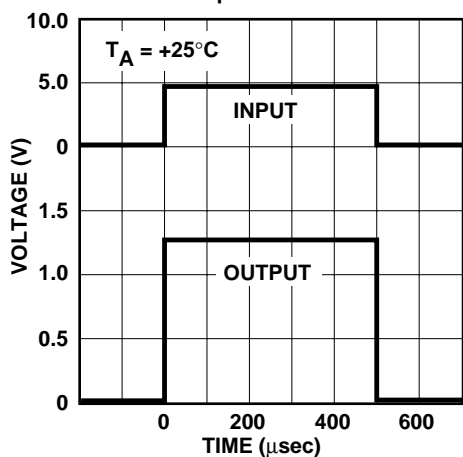
LM285/385-1.2V: Output Voltage Change vs Reverse Current



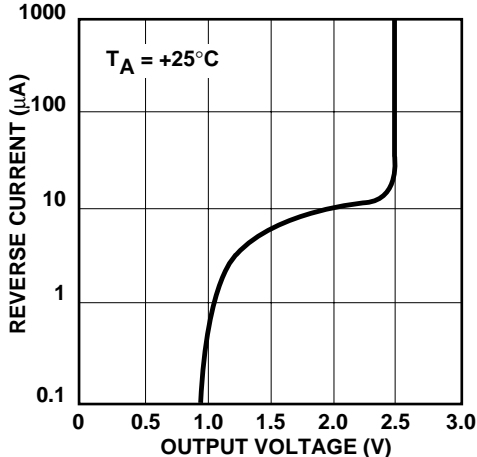
LM285/385-1.2V: Forward Voltage vs Forward Current



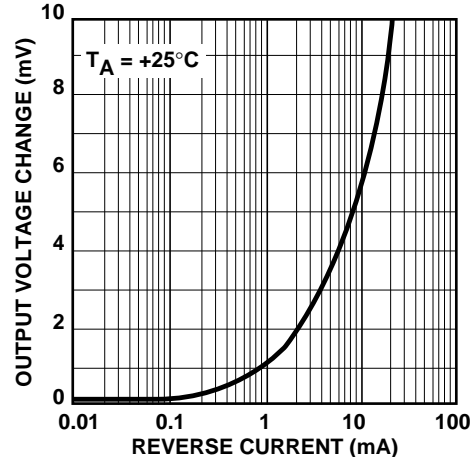
LM285/385-1.2V Response Time



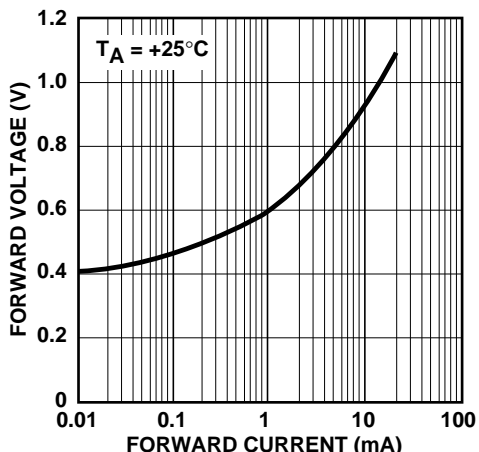
LM285/385-2.5V: Output Voltage vs Reverse Current



LM285/385-2.5V: Output Voltage Change vs Reverse Current



LM285/385-2.5V: Forward Voltage vs Forward Current



LM285/385-2.5V Response Time

